## NSN 5962-01-367-1285

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View Online at https://aerobasegroup.com/nsn/5962-01-367-1285

Between 1.270 inches and 1.290 inches

**Body Width:** 

Between 0.300 inches and 0.320 inches

**Body Height:** 

Between 0.190 inches and 0.210 inches

**Maximum Power Dissipation Rating:** 

650.0 milliwatts

**Operating Tempurature Range:** 

-55.0/+125.0 degrees celsius

**Storage Tempurature Range:** 

-65.0/+150.0 degrees celsius

**End Application:** 

Eo lorops

**Features Provided:** 

Erasable and programmed and ultraviolet erasable and electrostatic sensitive

**Inclosure Material:** 

Ceramic

**Inclosure Configuration:** 

Dual-in-line

**Output Logic Form:** 

Complementary-metal oxide-semiconductor logic

**Input Circuit Pattern:** 

22 input

**Criticality Code Justification:** 

Feat

**Case Outline Source And Designator:** 

D-9 mil-m-38510

**Terminal Surface Treatment:** 

Solder

**Product Name:** 

Microcircuit, programmed

Voltage Rating And Type Per Characteristic:

-2.0 volts total supply and 7.0 volts total supply

**Time Rating Per Chacteristic:** 

55.00 nanoseconds af output megawatts

**Memory Device Type:** 

Pal

**Special Features:** 

Esd; altered item programmed using 67268/5962-8686401lx using file 1055\_u62.Jed with check sum 3c24

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Ī	erminal	Type	And	Quant	tity:

24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0